


AMENDMENTS TO THE SPECIFICATION

Please amend paragraph [0026] to reintroduce subscript notations that were lost during electronic (EFS) filing as follows:

---

 [0026] The group III-nitride compound 20 of the preferred embodiment includes binary compound materials of, for example, GaN, InN, AlN, ternary compound materials of, for example,  $\text{In}_x\text{Ga}_{1-x}\text{N}$ ,  $\text{Al}_y\text{Ga}_{1-y}\text{N}$ ,  $\text{In}_z\text{Al}_{1-z}\text{N}$  and/or quaternary compound materials of, for example,  $\text{In}_u\text{Al}_v\text{Ga}_{1-u-v}\text{N}$ , where  $u$ ,  $v$ ,  $x$ ,  $y$ , and  $z$  are fractional numbers between zero (0) and (1) exclusive and  $u+v$  is a fractional number between zero (0) and (1) exclusive. Such group III-nitride compounds 20 are preferred as providing blue or ultraviolet emission (i.e., wavelengths below about 500 nm), having good reliability, and benefiting from a relatively mature processing technology. In the preferred embodiment, the group III-nitride compound 20 includes GaN. However, other materials are contemplated.

---